

## 阅读申明

- 1.本站收集的数据手册和产品资料都来自互联网，版权归原作者所有。如读者和版权方有任何异议请及时告之，我们将妥善解决。
- 2.本站提供的中文数据手册是英文数据手册的中文翻译，其目的是协助用户阅读，该译文无法自动跟随原稿更新，同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。
- 3.本站提供的产品资料，来自厂商的技术支持或者使用者的心得体会等，其内容可能存在描述上的差异，建议读者做出适当判断。
- 4.如需与我们联系，请发邮件到marketing@iczoom.com，主题请标有“数据手册”字样。

## Read Statement

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.
2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.
3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.
4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets" .

# Medium Power Transistor (-32V, -1A)

2SB1132 / 2SA1515S / 2SB1237

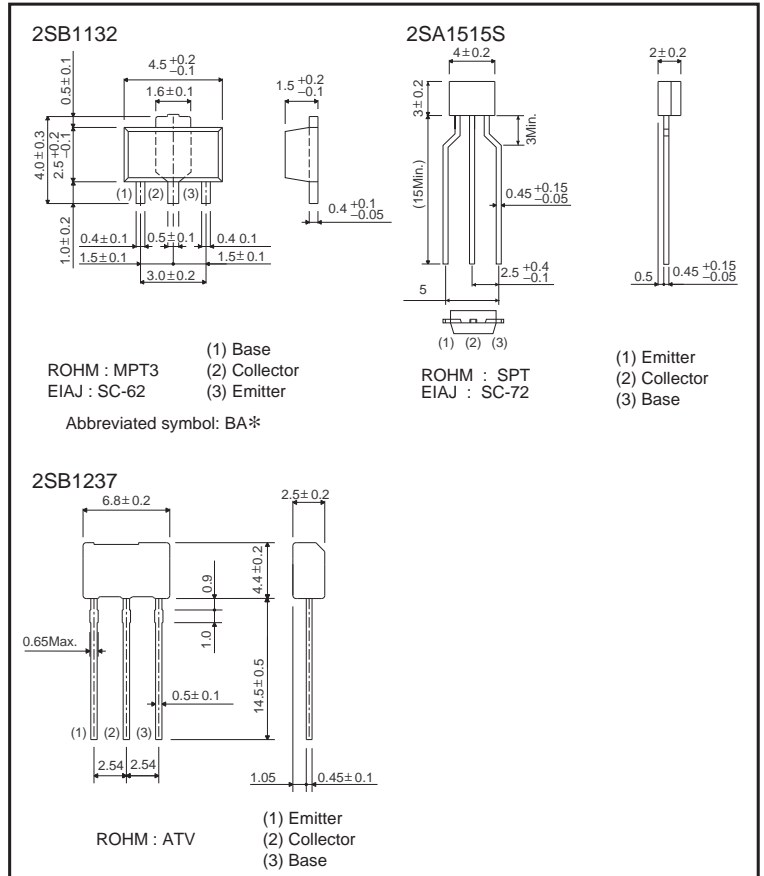
●Features

- 1) Low  $V_{CE(sat)}$ .  
 $V_{CE(sat)} = -0.2V(Typ.)$   
( $I_C / I_B = -500mA / -50mA$ )
- 2) Compliments 2SD1664 /  
2SD1858

●Structure

Epitaxial planar type  
PNP silicon transistor

●Dimensions (Unit : mm)



\* Denotes  $h_{FE}$

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V <sub>CB0</sub>	-40	V
Collector-emitter voltage	V <sub>CE0</sub>	-32	V
Emitter-base voltage	V <sub>EB0</sub>	-5	V
Collector current	I <sub>c</sub>	-1	A(DC)
		-2	A(Pulse) *1
Collector power dissipation	P <sub>c</sub>	0.5	W *2
		2	
		0.3	
	2SB1237	1	*3
Junction temperature	T <sub>j</sub>	150	°C
Storage temperature	T <sub>stg</sub>	-55 to +150	°C

\*1 Single pulse, Pw=100ms

\*2 When mounted on a 40×40×0.7 mm ceramic board.

\*3 Printed circuit board, 1.7 mm thick, collector copper plating 100mm<sup>2</sup> or larger.

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions	
Collector-base breakdown voltage	BV <sub>CB0</sub>	-40	-	-	V	I <sub>c</sub> = -50μA	
Collector-emitter breakdown voltage	BV <sub>CE0</sub>	-32	-	-	V	I <sub>c</sub> = -1mA	
Emitter-base breakdown voltage	BV <sub>EB0</sub>	-5	-	-	V	I <sub>E</sub> = -50μA	
Collector cutoff current	I <sub>CB0</sub>	-	-	-0.5	μA	V <sub>CB</sub> = -20V	
Emitter cutoff current	I <sub>EB0</sub>	-	-	-0.5	μA	V <sub>EB</sub> = -4V	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	-	-0.2	-0.5	V	I <sub>c</sub> /I <sub>B</sub> = -500mA/-50mA *	
DC current transfer ratio	2SB1132, 2SB1237	h <sub>FE</sub>	120	-	390	-	V <sub>CE</sub> = -3V, I <sub>c</sub> = -0.1A *
	2SA1515S		120	-	390	-	
Transition frequency	f <sub>t</sub>	-	150	-	MHz	V <sub>CE</sub> = -5V, I <sub>E</sub> =50mA, f=30MHz	
Output capacitance	C <sub>ob</sub>	-	20	30	pF	V <sub>CB</sub> = -10V, I <sub>E</sub> =0A, f=1MHz	

\* Measured using pulse current.

●Packaging specifications and h<sub>FE</sub>

Type	h <sub>FE</sub>	Package	Taping		
		Code	T100	TP	TU2
		Basic ordering unit (pieces)	1000	5000	2500
2SB1132	QR		○	-	-
2SA1515S	QR		-	○	-
2SB1237	QR		-	-	○

h<sub>FE</sub> values are classified as follows :

Item	Q	R
h <sub>FE</sub>	120 to 270	180 to 390

●Electrical characteristics curves

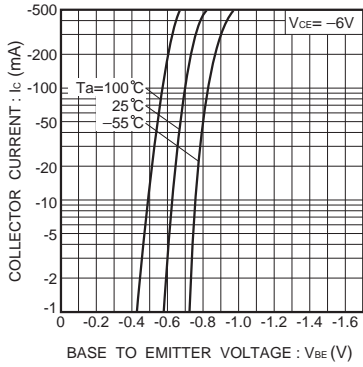


Fig.1 Grounded emitter propagation characteristics

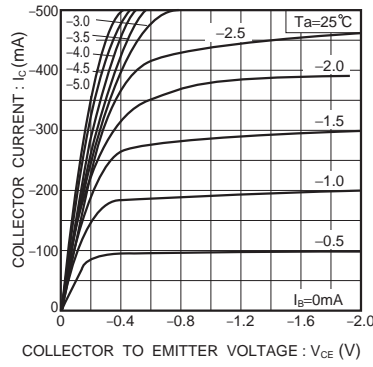


Fig.2 Grounded emitter output characteristics

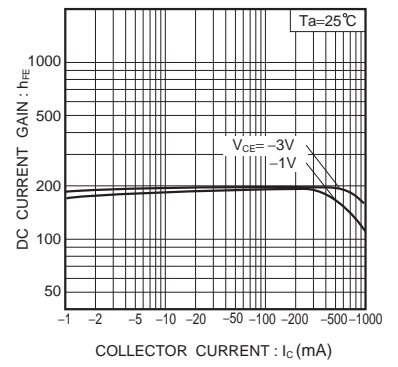


Fig.3 DC current gain vs. collector current(I)

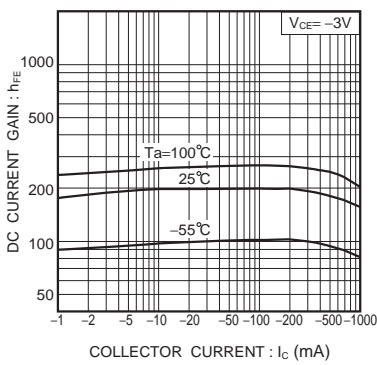


Fig.4 DC current gain vs. collector current(II)

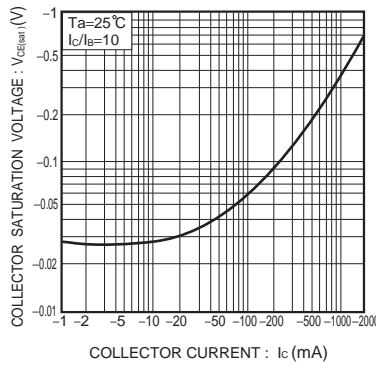


Fig.5 Collector-emitter saturation voltage vs. collector current

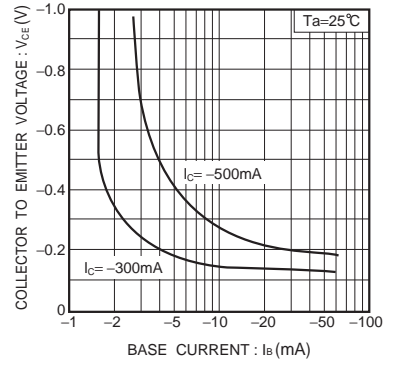


Fig.6 Collector-emitter saturation voltage vs. base current

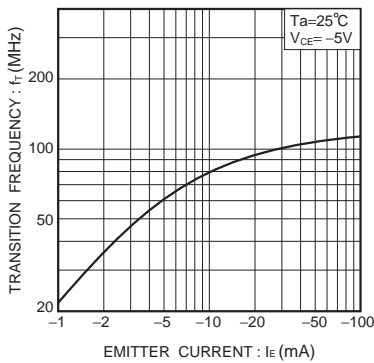


Fig.7 Gain bandwidth product vs. emitter current

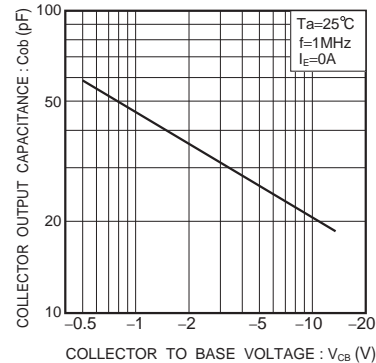


Fig.8 Collector output capacitance vs. collector-base voltage

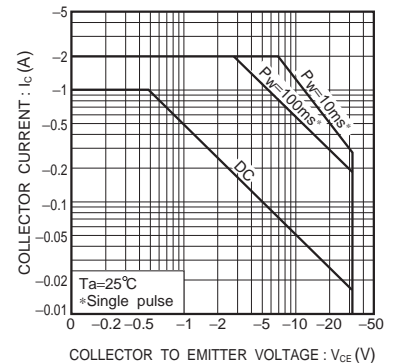


Fig.9 Safe operation area (2SB1132)

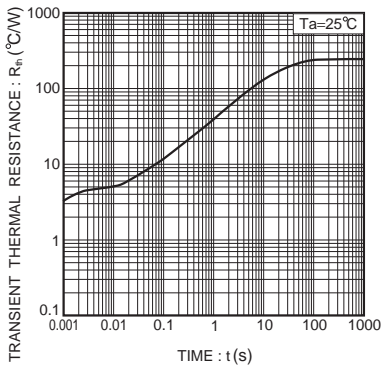


Fig.10 Transient thermal resistance (2SB1132)

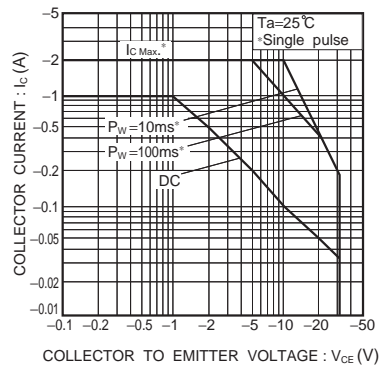


Fig.11 Safe operation area (2SB1237)

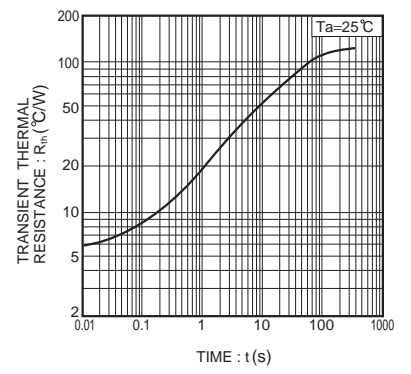


Fig.12 Transient thermal resistance (2SB1237)

## Notes

No copying or reproduction of this document, in part or in whole, is permitted without the consent of ROHM Co.,Ltd.

The content specified herein is subject to change for improvement without notice.

The content specified herein is for the purpose of introducing ROHM's products (hereinafter "Products"). If you wish to use any such Product, please be sure to refer to the specifications, which can be obtained from ROHM upon request.

Examples of application circuits, circuit constants and any other information contained herein illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

Great care was taken in ensuring the accuracy of the information specified in this document. However, should you incur any damage arising from any inaccuracy or misprint of such information, ROHM shall bear no responsibility for such damage.

The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM and other parties. ROHM shall bear no responsibility whatsoever for any dispute arising from the use of such technical information.

The Products specified in this document are intended to be used with general-use electronic equipment or devices (such as audio visual equipment, office-automation equipment, communication devices, electronic appliances and amusement devices).

The Products specified in this document are not designed to be radiation tolerant.

While ROHM always makes efforts to enhance the quality and reliability of its Products, a Product may fail or malfunction for a variety of reasons.

Please be sure to implement in your equipment using the Products safety measures to guard against the possibility of physical injury, fire or any other damage caused in the event of the failure of any Product, such as derating, redundancy, fire control and fail-safe designs. ROHM shall bear no responsibility whatsoever for your use of any Product outside of the prescribed scope or not in accordance with the instruction manual.

The Products are not designed or manufactured to be used with any equipment, device or system which requires an extremely high level of reliability the failure or malfunction of which may result in a direct threat to human life or create a risk of human injury (such as a medical instrument, transportation equipment, aerospace machinery, nuclear-reactor controller, fuel-controller or other safety device). ROHM shall bear no responsibility in any way for use of any of the Products for the above special purposes. If a Product is intended to be used for any such special purpose, please contact a ROHM sales representative before purchasing.

If you intend to export or ship overseas any Product or technology specified herein that may be controlled under the Foreign Exchange and the Foreign Trade Law, you will be required to obtain a license or permit under the Law.



Thank you for your accessing to ROHM product informations.  
More detail product informations and catalogs are available, please contact us.

## ROHM Customer Support System

<http://www.rohm.com/contact/>